

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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**P-CHANNEL MOS FIELD EFFECT TRANSISTOR  
FOR SWITCHING**

**DESCRIPTION**

The μPA651TT is a switching device, which can be driven directly by a 1.8 V power source.

This device features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

**FEATURES**

- 1.8 V drive available
- Low on-state resistance  
 $R_{DS(on)1} = 69 \text{ m}\Omega \text{ MAX. (} V_{GS} = -4.5 \text{ V, } I_D = -2.5 \text{ A)}$   
 $R_{DS(on)2} = 88 \text{ m}\Omega \text{ MAX. (} V_{GS} = -2.5 \text{ V, } I_D = -2.5 \text{ A)}$   
 $R_{DS(on)3} = 142 \text{ m}\Omega \text{ MAX. (} V_{GS} = -1.8 \text{ V, } I_D = -1.5 \text{ A)}$

**ORDERING INFORMATION**

| PART NUMBER | PACKAGE         |
|-------------|-----------------|
| μPA651TT    | 6pinWSOF (1620) |

Marking: WE

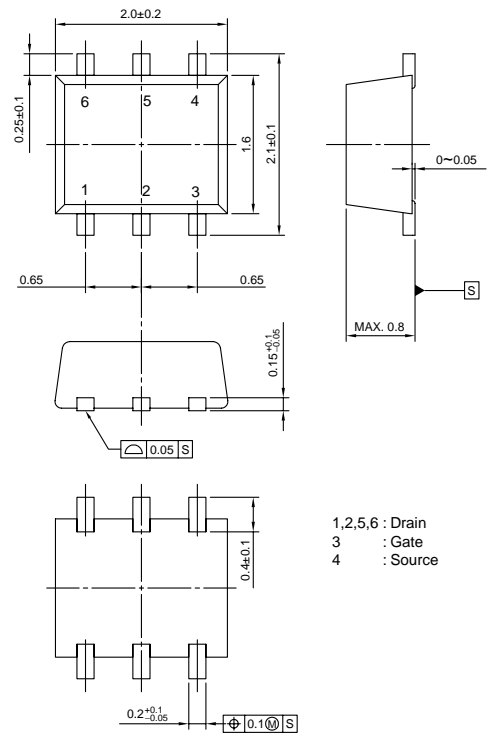
**ABSOLUTE MAXIMUM RATINGS (TA = 25°C)**

|  |                       |             |    |
|--|-----------------------|-------------|----|
| Drain to Source Voltage (VGS = 0 V)                  | V <sub>DSS</sub>      | -20         | V  |
| Gate to Source Voltage (VDS = 0 V)                   | V <sub>GSS</sub>      | ±8.0        | V  |
| Drain Current (DC) (TA = 25°C)                       | I <sub>D(DC)</sub>    | ±5.0        | A  |
| Drain Current (pulse) <sup>Note1</sup>               | I <sub>D(pulse)</sub> | ±20         | A  |
| Total Power Dissipation (TA = 25°C)                  | P <sub>T1</sub>       | 0.2         | W  |
| Total Power Dissipation (TA = 25°C) <sup>Note2</sup> | P <sub>T2</sub>       | 1.4         | W  |
| Channel Temperature                                  | T <sub>ch</sub>       | 150         | °C |
| Storage Temperature                                  | T <sub>stg</sub>      | -55 to +150 | °C |

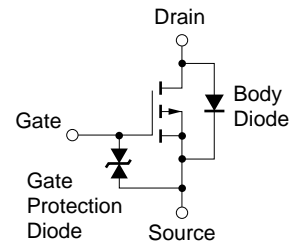
- Notes**
1. PW ≤ 10 μs, Duty Cycle ≤ 1%
  2. Mounted on FR-4 board, t ≤ 5 sec.

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

**PACKAGE DRAWING (Unit: mm)**



**EQUIVALENT CIRCUIT**

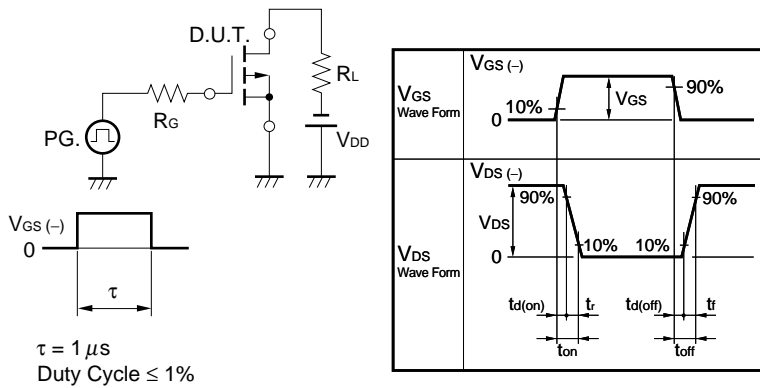


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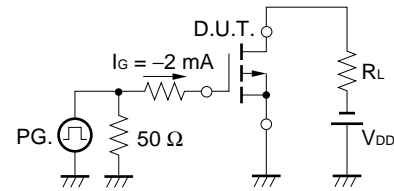
**ELECTRICAL CHARACTERISTICS (TA = 25°C)**

| CHARACTERISTICS                     | SYMBOL        | TEST CONDITIONS                                  | MIN.  | TYP. | MAX. | UNIT |
|-------------------------------------|---------------|--|-------|------|------|------|
| Zero Gate Voltage Drain Current     | $I_{DSS}$     | $V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}$     |       |      | -10  | μA   |
| Gate Leakage Current                | $I_{GSS}$     | $V_{GS} = \mp 8.0\text{ V}, V_{DS} = 0\text{ V}$ |       |      | ±10  | μA   |
| Gate Cut-off Voltage                | $V_{GS(off)}$ | $V_{DS} = -10\text{ V}, I_D = -1.0\text{ mA}$    | -0.45 |      | -1.5 | V    |
| Forward Transfer Admittance         | $ y_{fs} $    | $V_{DS} = -10\text{ V}, I_D = -2.5\text{ A}$     | 4.0   |      |      | S    |
| Drain to Source On-state Resistance | $R_{DS(on)1}$ | $V_{GS} = -4.5\text{ V}, I_D = -2.5\text{ A}$    |       | 55   | 69   | mΩ   |
|                                     | $R_{DS(on)2}$ | $V_{GS} = -2.5\text{ V}, I_D = -2.5\text{ A}$    |       | 66   | 88   | mΩ   |
|                                     | $R_{DS(on)3}$ | $V_{GS} = -1.8\text{ V}, I_D = -1.5\text{ A}$    |       | 85   | 142  | mΩ   |
| Input Capacitance                   | $C_{iss}$     | $V_{DS} = -10\text{ V}$                          |       | 600  |      | pF   |
| Output Capacitance                  | $C_{oss}$     | $V_{GS} = 0\text{ V}$                            |       | 120  |      | pF   |
| Reverse Transfer Capacitance        | $C_{rss}$     | $f = 1.0\text{ MHz}$                             |       | 75   |      | pF   |
| Turn-on Delay Time                  | $t_{d(on)}$   | $V_{DD} = -10\text{ V}, I_D = -2.5\text{ A}$     |       | 45   |      | ns   |
| Rise Time                           | $t_r$         | $V_{GS} = -4.0\text{ V}$                         |       | 200  |      | ns   |
| Turn-off Delay Time                 | $t_{d(off)}$  | $R_G = 10\text{ }\Omega$                         |       | 435  |      | ns   |
| Fall Time                           | $t_f$         |  |       | 345  |      | ns   |
| Total Gate Charge                   | $Q_G$         | $V_{DD} = -16\text{ V}$                          |       | 5.5  |      | nC   |
| Gate to Source Charge               | $Q_{GS}$      | $V_{GS} = -4.0\text{ V}$                         |       | 1.2  |      | nC   |
| Gate to Drain Charge                | $Q_{GD}$      | $I_D = -5.0\text{ A}$                            |       | 2.1  |      | nC   |
| Body Diode Forward Voltage          | $V_{F(S-D)}$  | $I_F = 5.0\text{ A}, V_{GS} = 0\text{ V}$        |       | 0.94 |      | V    |

**TEST CIRCUIT 1 SWITCHING TIME**

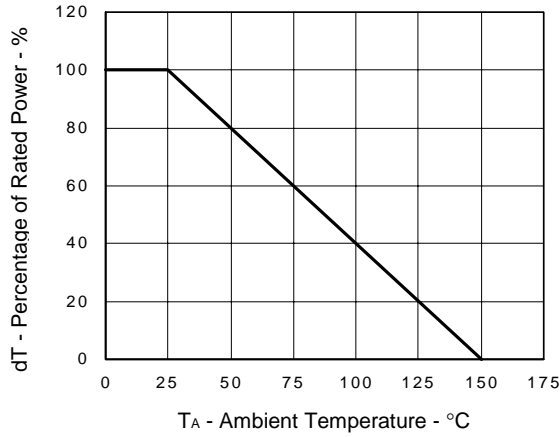


**TEST CIRCUIT 2 GATE CHARGE**

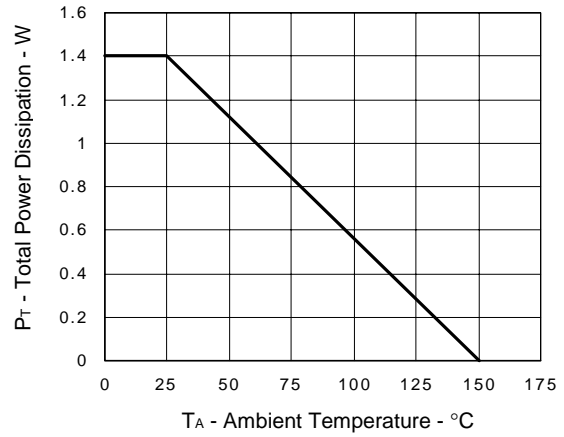


TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

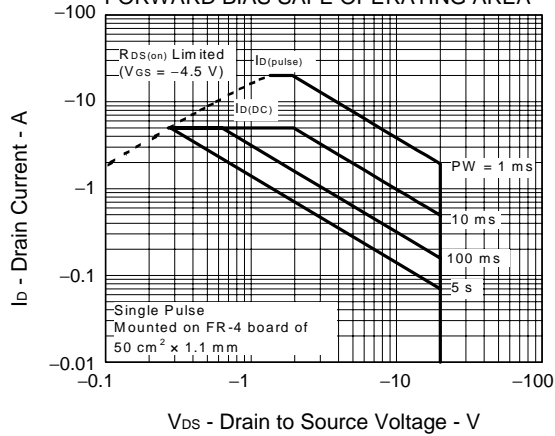
DERATING FACTOR FORWARD BIAS  
SAFE OPERATING AREA



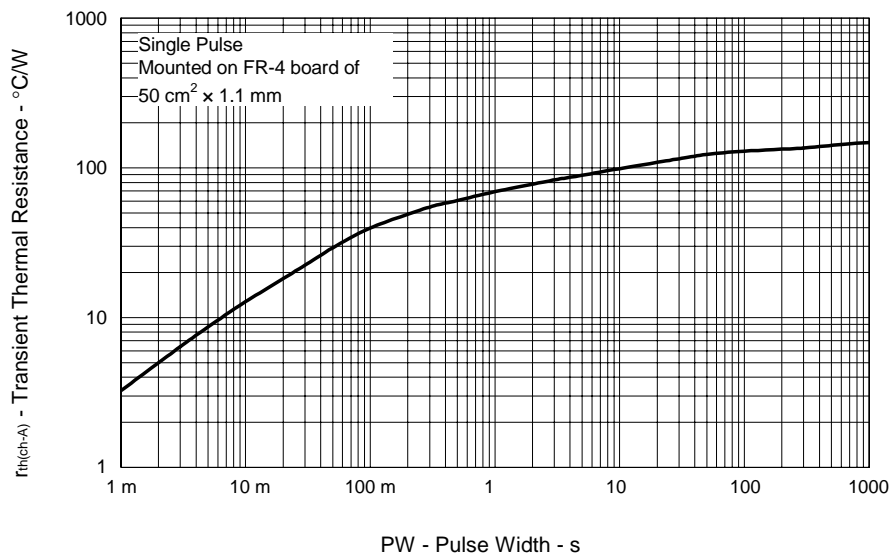
TOTAL POWER DISSIPATION vs.  
AMBIENT TEMPERATURE



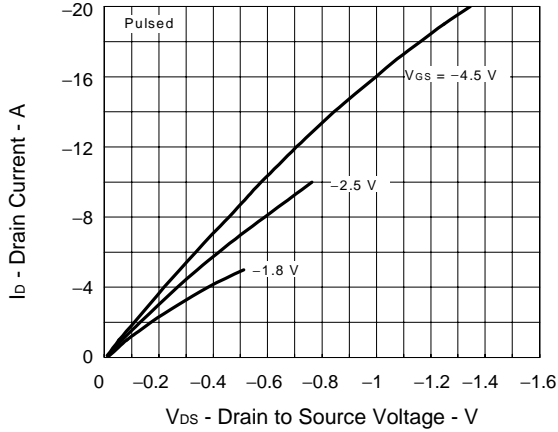
FORWARD BIAS SAFE OPERATING AREA



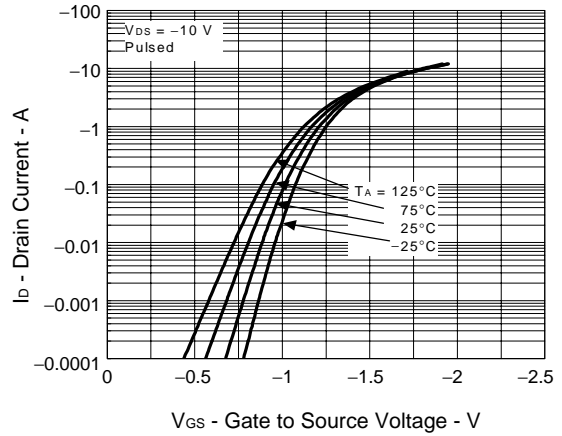
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



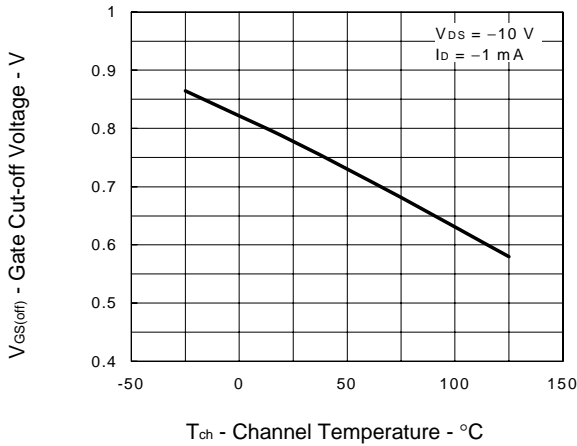
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



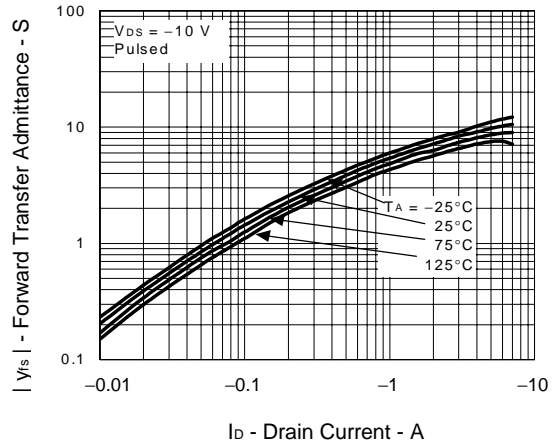
FORWARD TRANSFER CHARACTERISTICS



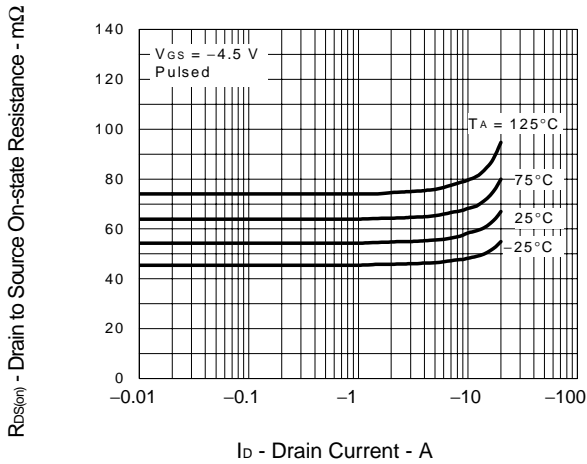
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



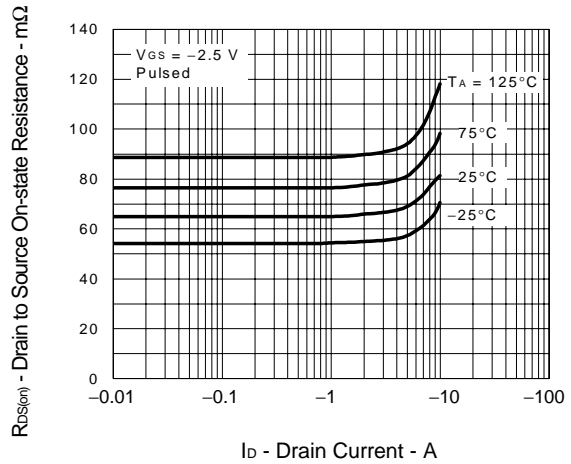
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

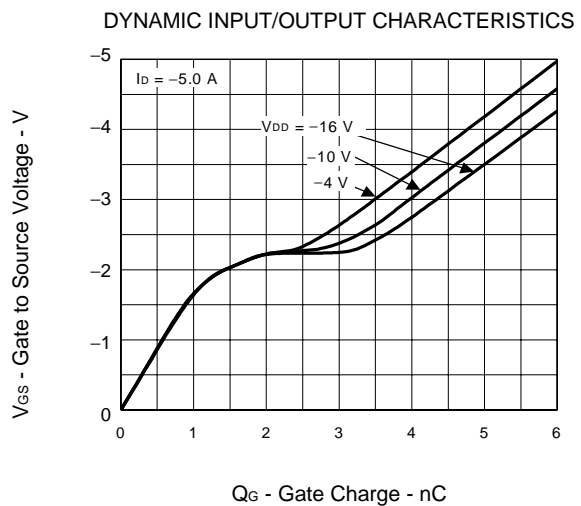
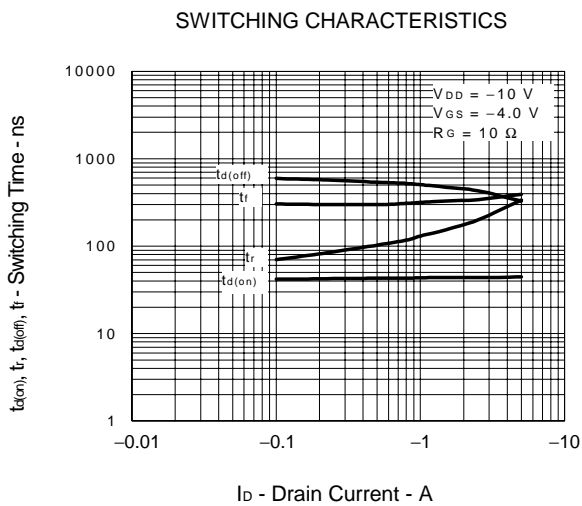
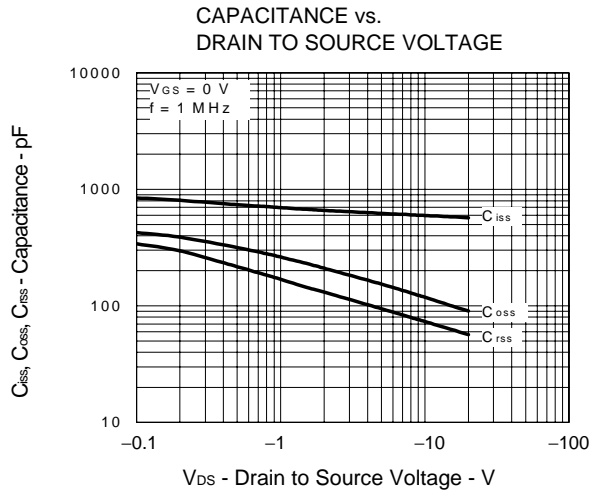
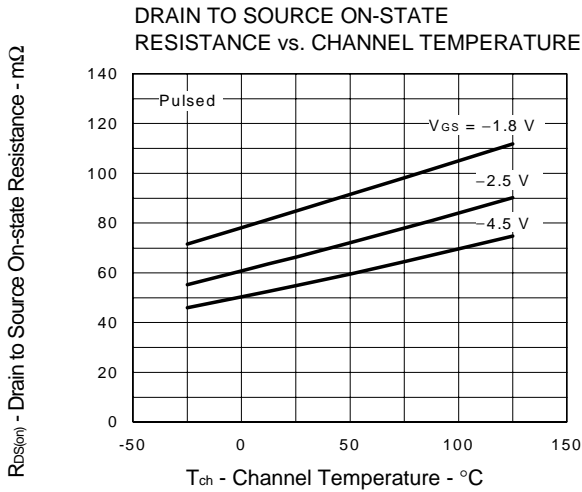
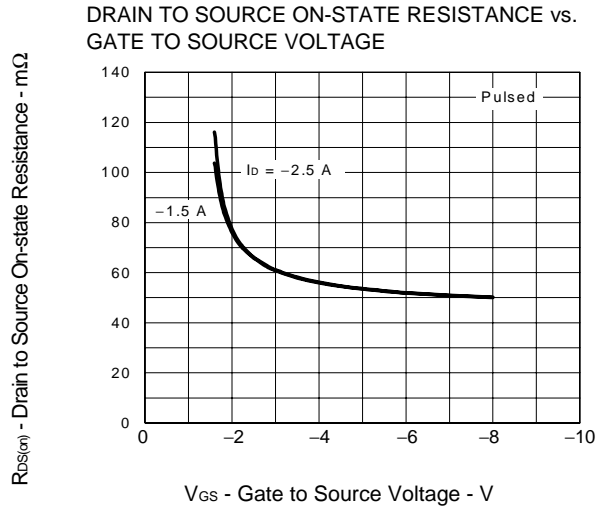
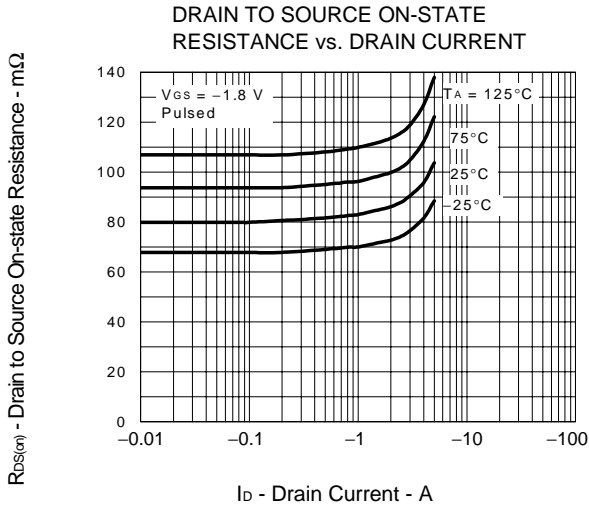


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

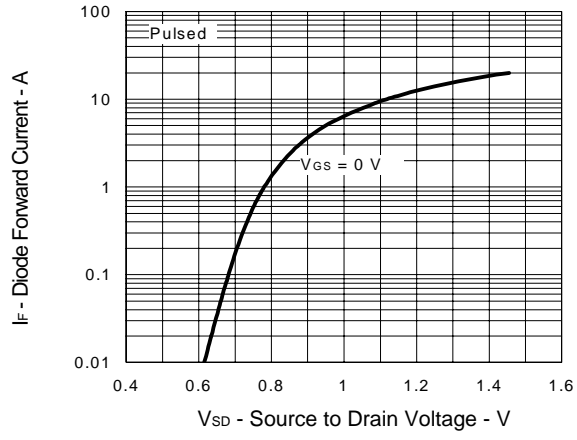


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT





SOURCE TO DRAIN DIODE FORWARD VOLTAGE





[MEMO]

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